



# STB18NM80, STF18NM80 STP18NM80, STW18NM80

N-channel 800 V, 0.25 Ω, 17 A, MDmesh™ Power MOSFET  
D<sup>2</sup>PAK, TO-220FP, TO-220, TO-247

## Features

Type	V <sub>DSS</sub> (@T <sub>jmax</sub> )	R <sub>D(on)</sub> max	I <sub>D</sub>
STB18NM80	800 V	< 0.295 Ω	17 A
STF18NM80	800 V	< 0.295 Ω	17 A
STP18NM80	800 V	< 0.295 Ω	17 A <sup>(1)</sup>
STW18NM80	800 V	< 0.295 Ω	17 A

1. Limited only by maximum temperature allowed
- 100% avalanche tested
- Low input capacitance and gate charge
- Low gate input resistance

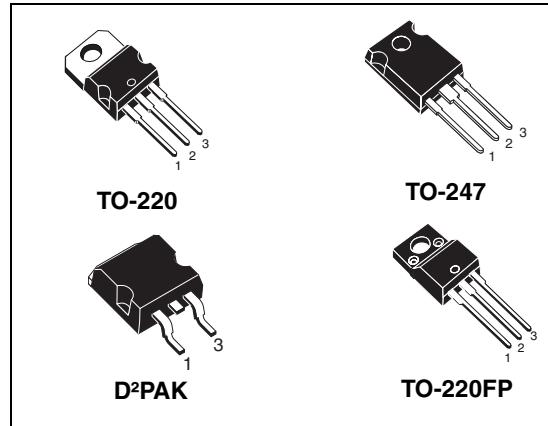


Figure 1. Internal schematic diagram

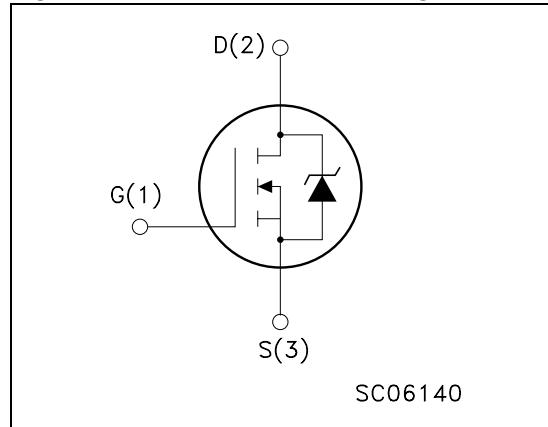


Table 1. Device summary

Order codes	Marking	Package	Packaging
STB18NM80	18NM80	D <sup>2</sup> PAK	Tape and reel
STF18NM80	18NM80	TO-220FP	Tube
STP18NM80	18NM80	TO-220	Tube
STW18NM80	18NM80	TO-247	Tube

## Contents

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# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value				Unit
		TO-220	D <sup>2</sup> PAK	TO-247	TO-220FP	
V <sub>DS</sub>	Drain-source voltage ( $V_{GS} = 0$ )	800				V
V <sub>GS</sub>	Gate-source voltage	$\pm 30$				V
I <sub>D</sub>	Drain current (continuous) at $T_C = 25^\circ\text{C}$	17		17 <sup>(1)</sup>		A
I <sub>D</sub>	Drain current (continuous) at $T_C = 100^\circ\text{C}$	10.71		10.71 <sup>(1)</sup>		A
I <sub>DM</sub> <sup>(2)</sup>	Drain current (pulsed)	68		68 <sup>(1)</sup>		A
P <sub>TOT</sub>	Total dissipation at $T_C = 25^\circ\text{C}$	190		40		W
V <sub>ISO</sub>	Insulation withstand voltage (RMS) from all three leads to external heat sink ( $t = 1\text{ s}; T_C = 25^\circ\text{C}$ )			2500		V
T <sub>stg</sub>	Storage temperature	-65 to 150				°C
T <sub>j</sub>	Max. operating junction temperature	150				°C

1. Limited only by maximum temperature allowed

2. Pulse width limited by safe operating area

**Table 3. Thermal data**

Symbol	Parameter	Value				Unit
		TO-220	D <sup>2</sup> PAK	TO-247	TO-220FP	
R <sub>thj-case</sub>	Thermal resistance junction-case	0.66		3.13		°C/W
R <sub>thj-amb</sub>	Thermal resistance junction-amb	62.5		50	62.5	°C/W
R <sub>thj-pcb</sub>	Thermal resistance junction-pcb		30			°C/W
T <sub>I</sub>	Maximum lead temperature for soldering purpose	300				°C

**Table 4. Avalanche characteristics**

Symbol	Parameter	Max value	Unit
I <sub>AS</sub>	Avalanche current, repetitive or not-repetitive (pulse width limited by T <sub>j</sub> max)	4	A
E <sub>AS</sub>	Single pulse avalanche energy (starting T <sub>j</sub> = 25 °C, I <sub>D</sub> = I <sub>AS</sub> , V <sub>DD</sub> = 50 V)	600	mJ

## 2 Electrical characteristics

( $T_{CASE} = 25^\circ\text{C}$  unless otherwise specified)

**Table 5. On/off states**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 1 \text{ mA}, V_{GS} = 0$	800			V
$I_{DSS}$	Zero gate voltage drain current ( $V_{GS} = 0$ )	$V_{DS} = \text{Max rating}, V_{DS} = \text{Max rating}, T_c = 125^\circ\text{C}$			10 100	$\mu\text{A}$ $\mu\text{A}$
$I_{GSS}$	Gate body leakage current ( $V_{DS} = 0$ )	$V_{GS} = \pm 30 \text{ V}$			$\pm 100$	nA
$V_{GS(\text{th})}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	3	4	5	V
$R_{DS(\text{on})}$	Static drain-source on-resistance	$V_{GS} = 10\text{V}, I_D = 8.5 \text{ A}$		0.25	0.295	$\Omega$

**Table 6. Dynamic**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$g_{fs}^{(1)}$	Forward transconductance	$V_{DS} = 15 \text{ V}, I_D = 8.5 \text{ A}$	-	14	-	S
$C_{iss}$ $C_{oss}$ $C_{rss}$	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}, V_{GS} = 0$	- - 29	2070 210 29	-	pF pF pF
$C_{oss \text{ eq.}}^{(2)}$	Equivalent output capacitance	$V_{GS} = 0, V_{DS} = 0 \text{ to } 640 \text{ V}$	-	316	-	pF
$R_G$	Gate input resistance	$f = 1 \text{ MHz} \text{ Gate DC Bias} = 0$ Test Signal Level = 20 mV Open Drain	-	4	-	$\Omega$
$Q_g$ $Q_{gs}$ $Q_{gd}$	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 640 \text{ V}, I_D = 17 \text{ A}$ $V_{GS} = 10 \text{ V}$ (see Figure 17)	-	70 13 40	-	nC nC nC

1. Pulsed: pulse duration = 300 $\mu\text{s}$ , duty cycle 1.5%

2.  $C_{oss \text{ eq.}}$  is defined as a constant equivalent capacitance giving the same charging time as  $C_{oss}$  when  $V_{DS}$  increases from 0 to 80%  $V_{DSS}$

**Table 7. Switching times**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 400 \text{ V}$ , $I_D = 8.5 \text{ A}$ ,		18		ns
$t_r$	Rise time	$R_G = 4.7 \Omega$ , $V_{GS} = 10 \text{ V}$		28	-	ns
$t_{d(off)}$	Turn-off delay time	(see <a href="#">Figure 16</a> and <a href="#">Figure 21</a> )		96	-	ns
$t_f$	Fall time			50		ns

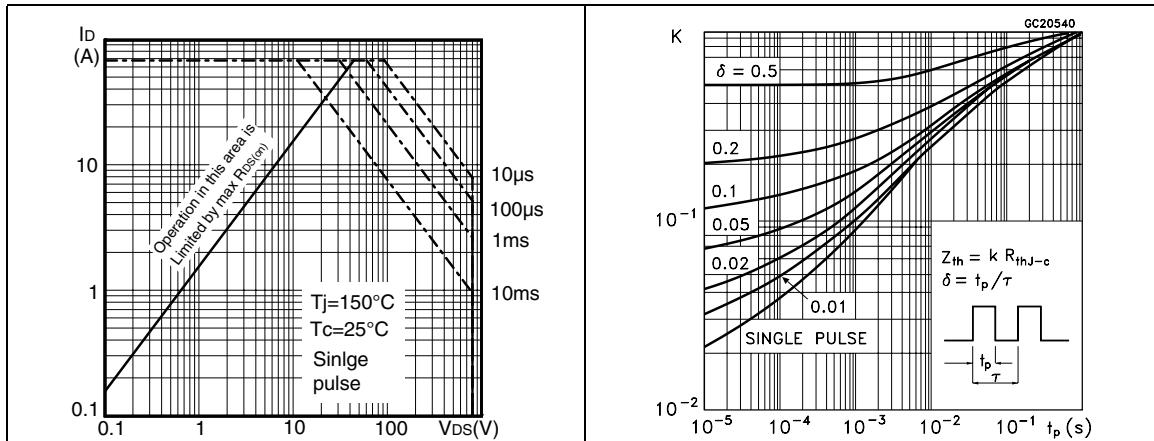
**Table 8. Source drain diode**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_{SD}$	Source-drain current		-		7	A
$I_{SDM}^{(1)}$	Source-drain current (pulsed)				28	A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD} = 17 \text{ A}$ , $V_{GS} = 0$	-		1.6	V
$t_{rr}$	Reverse recovery time	$I_{SD} = 17 \text{ A}$ , $dI/dt = 100 \text{ A}/\mu\text{s}$ , $V_{DD} = 100 \text{ V}$ ,		618		ns
$Q_{rr}$	Reverse recovery charge	(see <a href="#">Figure 18</a> )		9.6		$\mu\text{C}$
$I_{RRM}$	Reverse recovery current			31.2		A
$t_{rr}$	Reverse recovery time	$I_{SD} = 17 \text{ A}$ ,		822		ns
$Q_{rr}$	Reverse recovery charge	$dI/dt = 100 \text{ A}/\mu\text{s}$ ,		13		$\mu\text{C}$
$I_{RRM}$	Reverse recovery current	$V_{DD} = 100 \text{ V}$ , $T_j=150^\circ\text{C}$	-	31.8		A

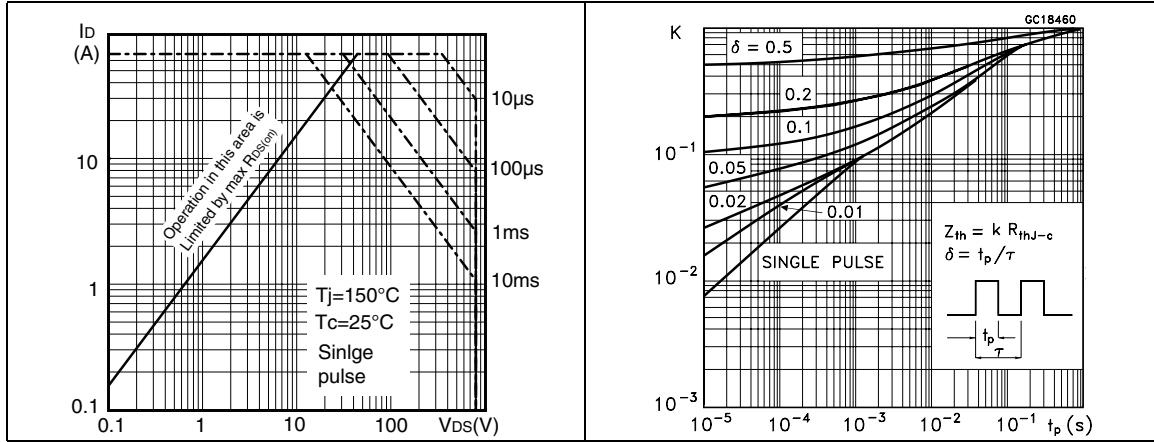
1. Pulse width limited by safe operating area
2. Pulsed: pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5%

## 2.1 Electrical characteristics (curves)

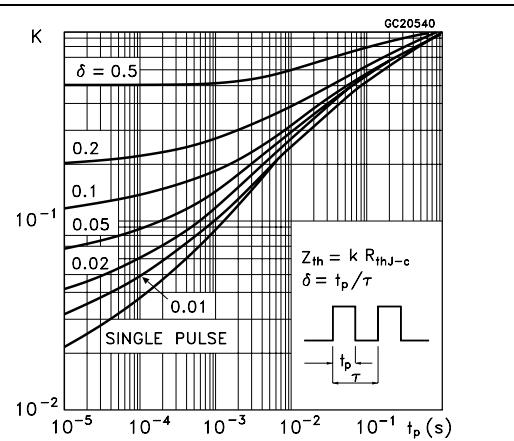
**Figure 2.** Safe operating area for TO-220, D<sup>2</sup>PAK



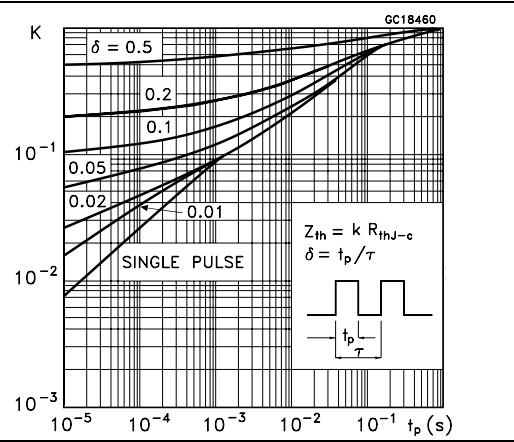
**Figure 4.** Safe operating area for TO-247



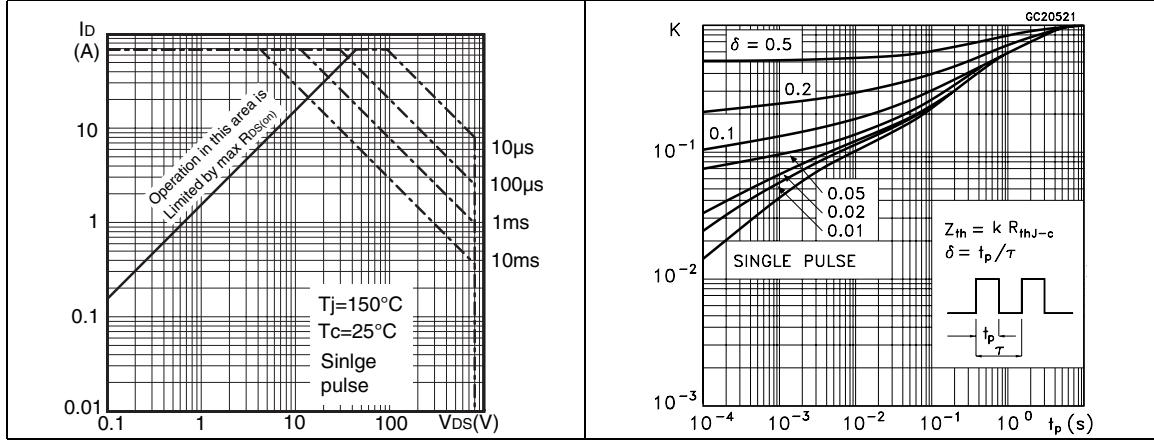
**Figure 3.** Thermal impedance for TO-220, D<sup>2</sup>PAK



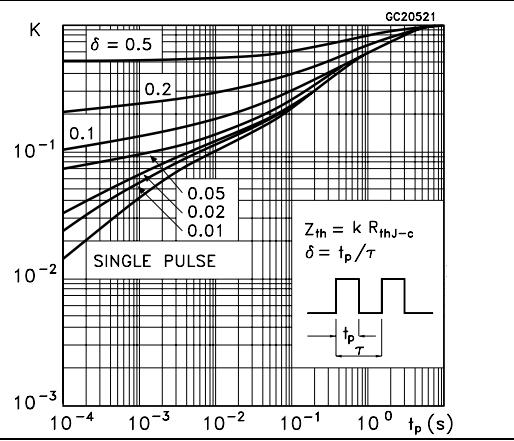
**Figure 5.** Thermal impedance for TO-247

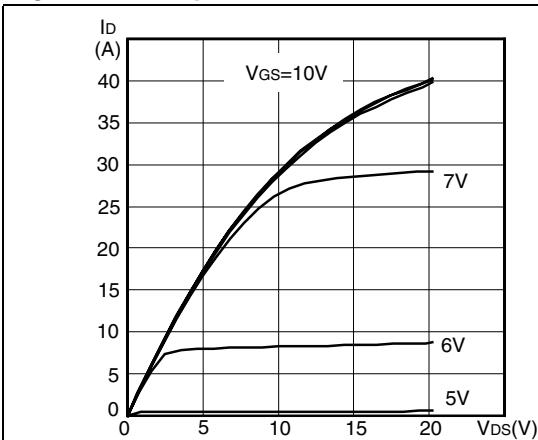
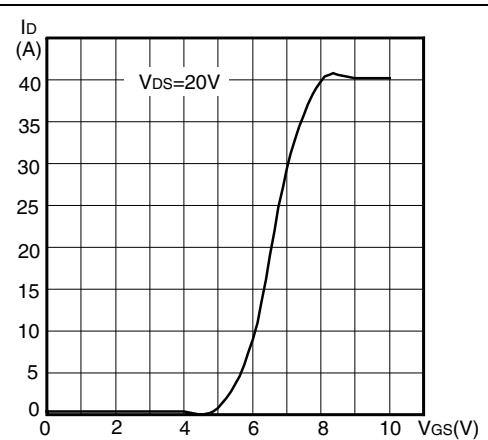
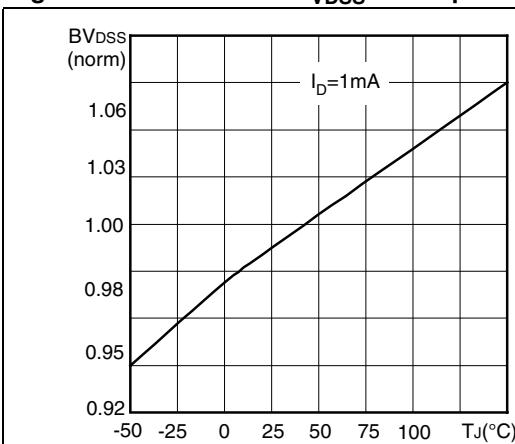
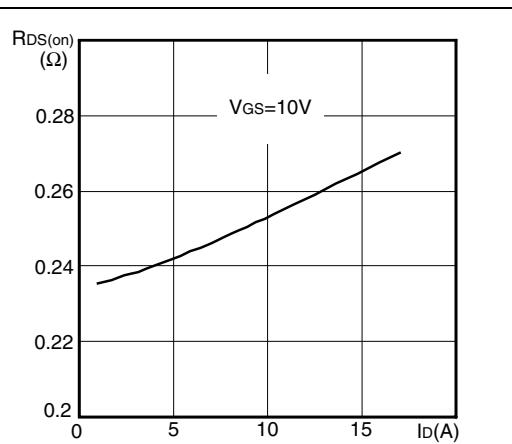
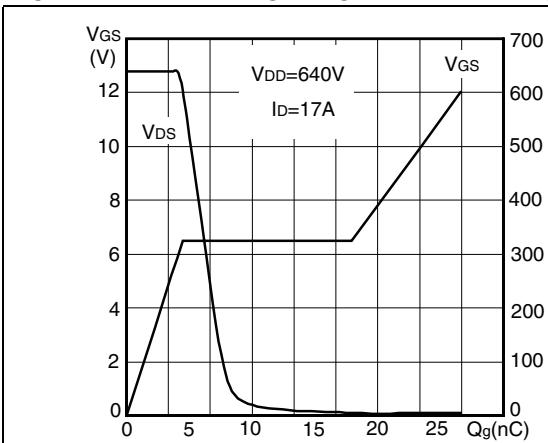
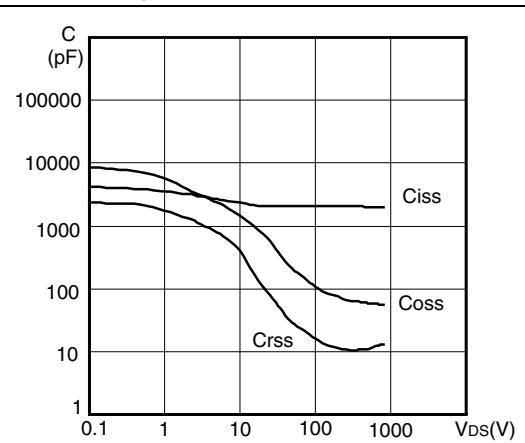


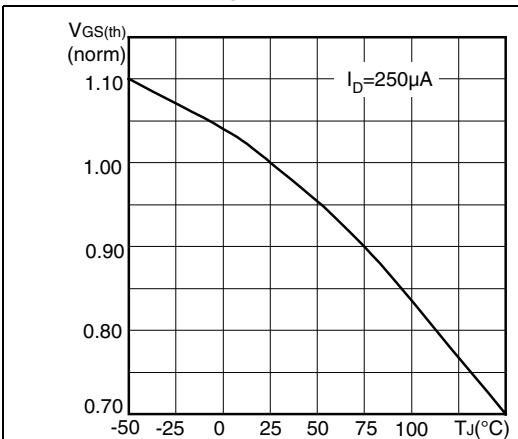
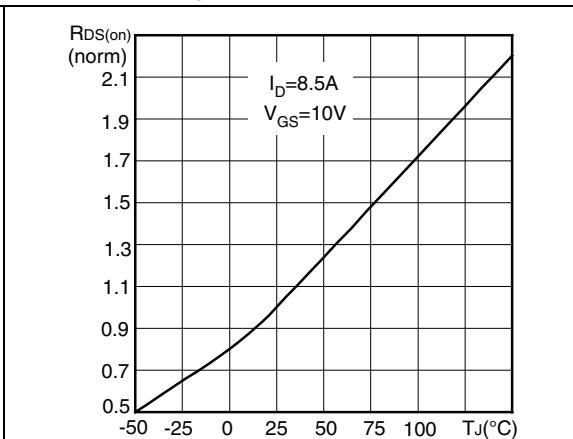
**Figure 6.** Safe operating area for TO-220FP



**Figure 7.** Thermal impedance for TO-220FP

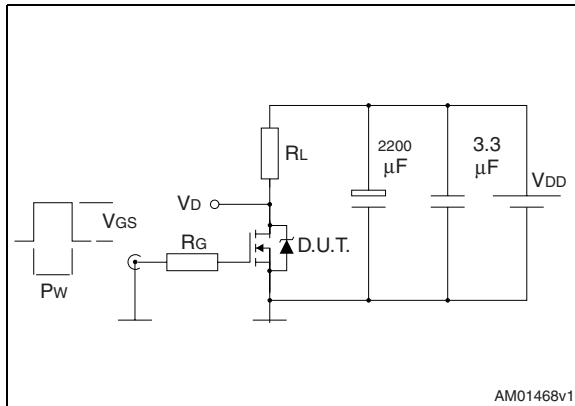


**Figure 8. Output characteristics****Figure 9. Transfer characteristics****Figure 10. Normalized  $B_{VDSS}$  vs temperature****Figure 11. Static drain-source on-resistance****Figure 12. Gate charge vs gate-source voltage****Figure 13. Capacitance variations**

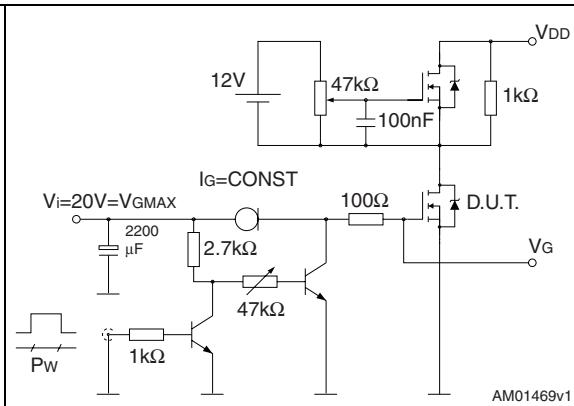
**Figure 14. Normalized gate threshold voltage vs temperature****Figure 15. Normalized on-resistance vs temperature**

### 3 Test circuits

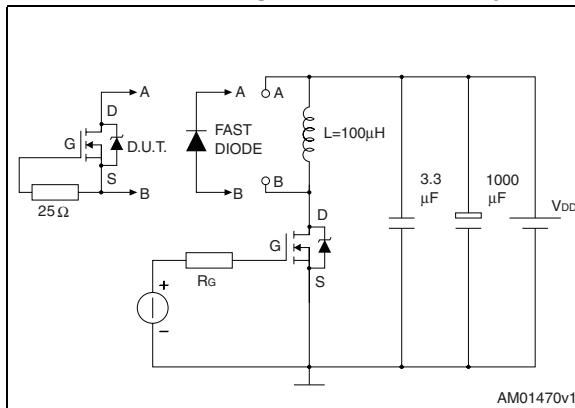
**Figure 16.** Switching times test circuit for resistive load



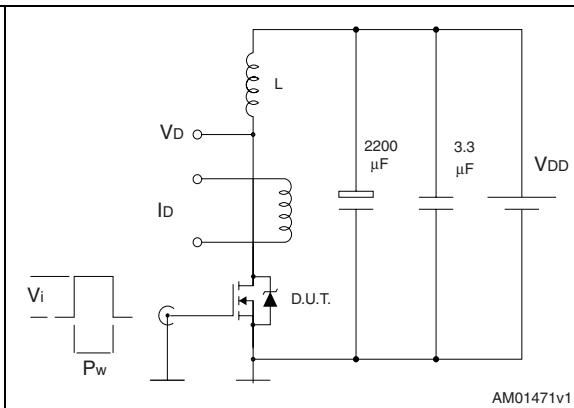
**Figure 17.** Gate charge test circuit



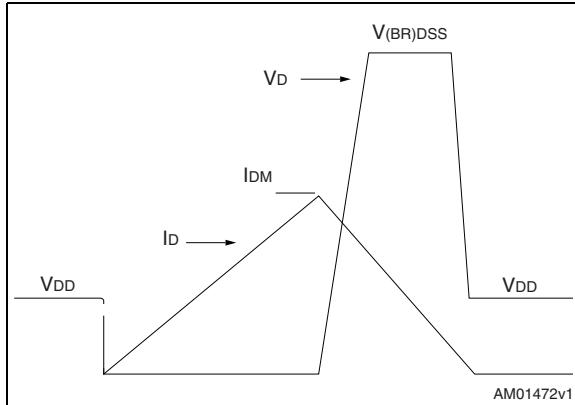
**Figure 18.** Test circuit for inductive load switching and diode recovery times



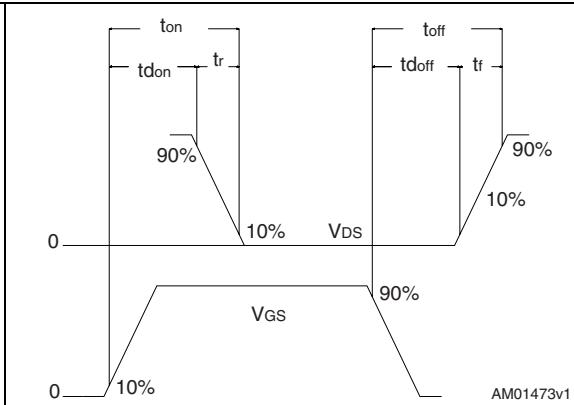
**Figure 19.** Unclamped inductive load test circuit



**Figure 20.** Unclamped inductive waveform



**Figure 21.** Switching time waveform

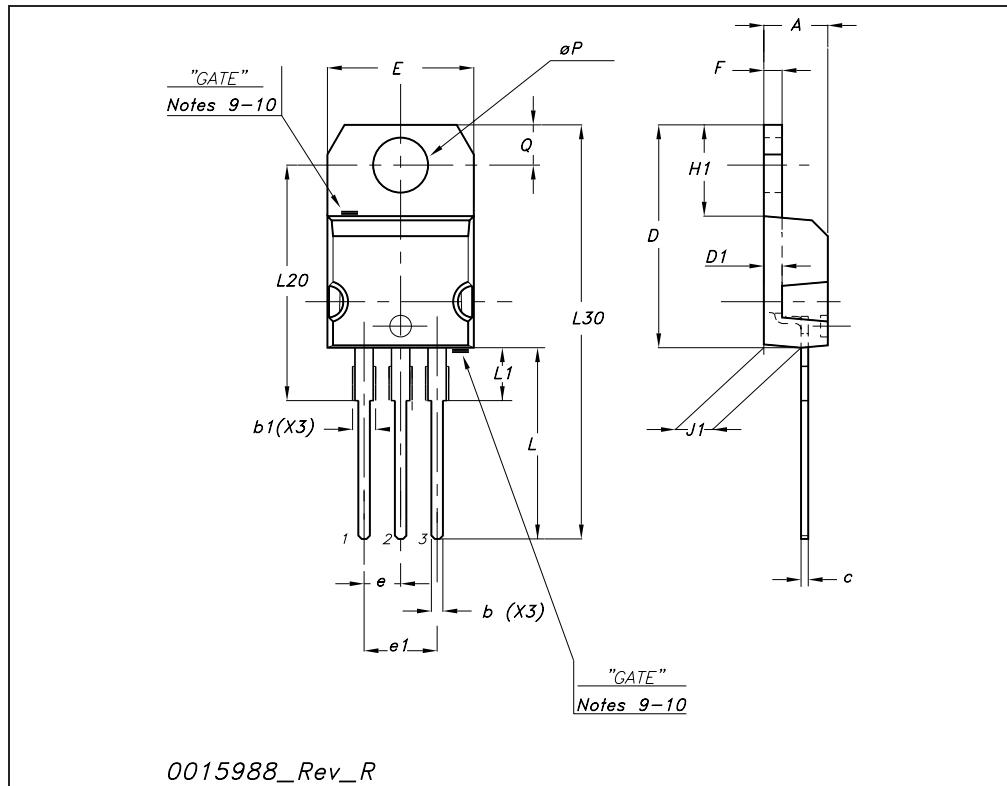


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
ECOPACK is an ST trademark.

## TO-220 mechanical data

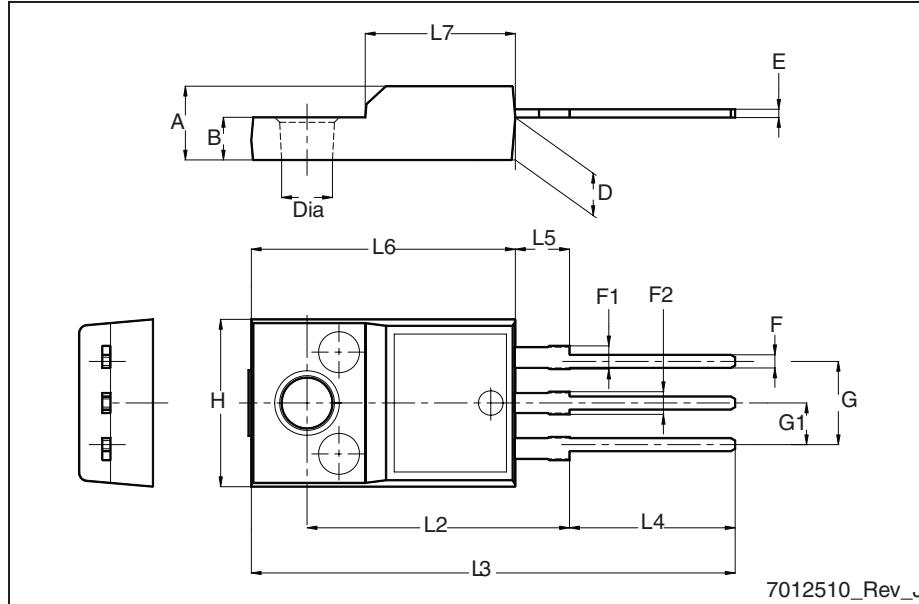
Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
$\emptyset P$	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



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## TO-220FP mechanical data

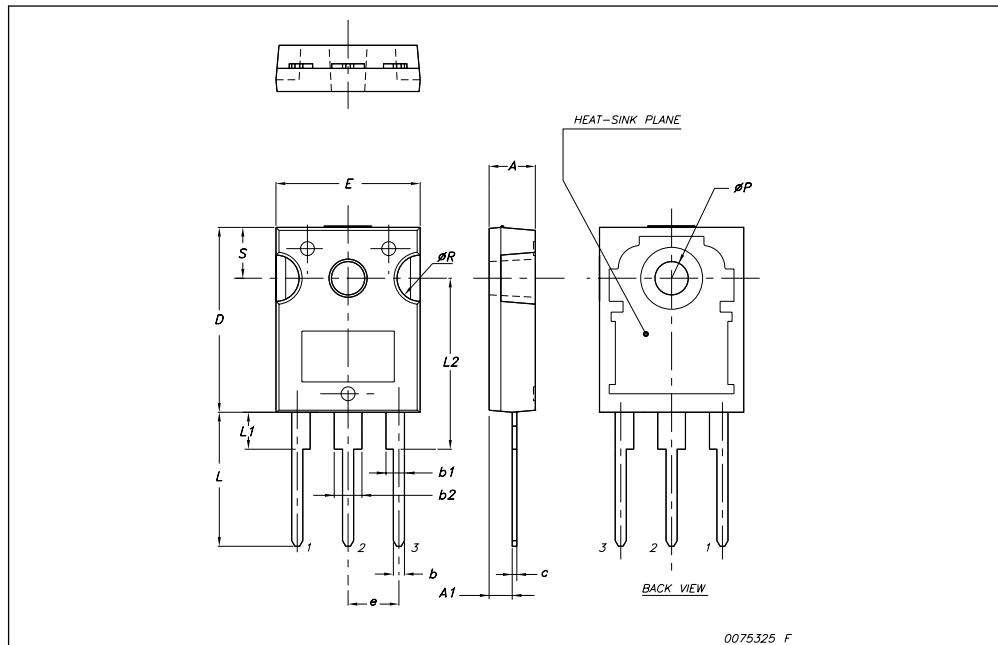
Dim.	mm		
	Min.	Typ.	Max.
A	4.4		4.6
B	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.5
G	4.95		5.2
G1	2.4		2.7
H	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2



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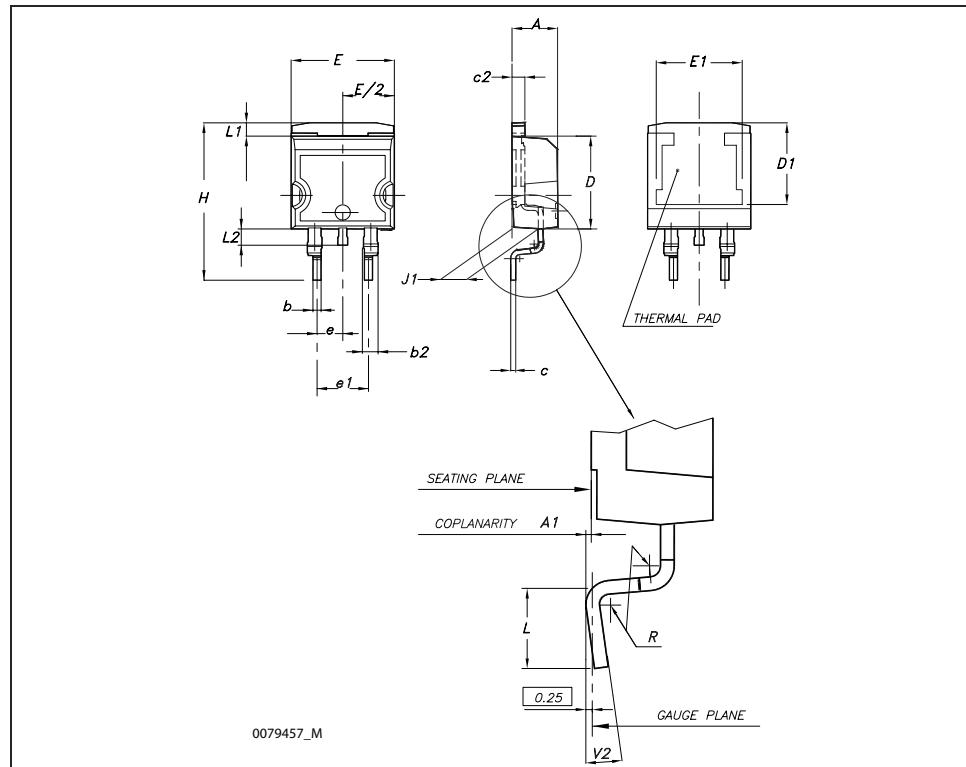
## TO-247 Mechanical data

Dim.	mm.		
	Min.	Typ	Max.
A	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
c	0.40		0.80
D	19.85		20.15
E	15.45		15.75
e		5.45	
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
øP	3.55		3.65
øR	4.50		5.50
S		5.50	

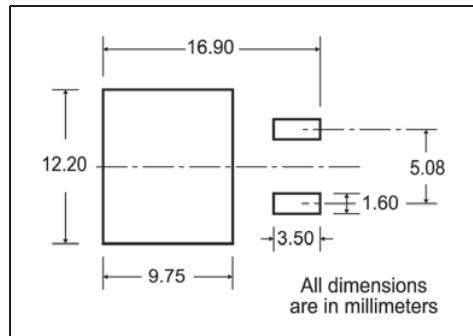


D<sup>2</sup>PAK (TO-263) mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
e		2.54			0.1	
e1	4.88		5.28	0.192		0.208
H	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



## 5 Packaging mechanical data

D<sup>2</sup>PAK FOOTPRINT

TAPE AND REEL SHIPMENT

REEL MECHANICAL DATA				
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0795	
G	24.4	26.4	0.960	1.039
N	100		3.937	
T		30.4		1.197

BASE QTY	BULK QTY
1000	1000

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A0	10.5	10.7	0.413	0.421
B0	15.7	15.9	0.618	0.626
D	1.5	1.6	0.059	0.063
D1	1.59	1.61	0.062	0.063
E	1.65	1.85	0.065	0.073
F	11.4	11.6	0.449	0.456
K0	4.8	5.0	0.189	0.197
P0	3.9	4.1	0.153	0.161
P1	11.9	12.1	0.468	0.476
P2	1.9	2.1	0.075	0.082
R	50		1.574	
T	0.25	0.35	0.0098	0.0137
W	23.7	24.3	0.933	0.956

40 mm min. Access hole at slot location

Full radius

Tape slot in core for tape start 25mm min. width

Center line of cavity

User Direction of Feed

FEED DIRECTION →

Bending radius R min.

## 6 Revision history

**Table 9. Document revision history**

Date	Revision	Changes
25-Feb-2009	1	First release
07-Apr-2009	2	<i>Section 4: Package mechanical data</i> has been modified
20-Apr-2009	3	$R_{DS(on)}$ max value has been corrected
09-Sep-2009	4	Document status promoted from preliminary data to datasheet

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